BCD-To-Seven Segment Latch/Decoder/Driver

The MC14511B BCD-to-seven segment latch/decoder/driver is constructed with complementary MOS (CMOS) enhancement mode devices and NPN bipolar output drivers in a single monolithic structure. The circuit provides the functions of a 4-bit storage latch, an 8421 BCD-to-seven segment decoder, and an output drive capability. Lamp test (LT), blanking (BI), and latch enable (LE) inputs are used to test the display, to turn-off or pulse modulate the brightness of the display, and to store a BCD code, respectively. It can be used with seven-segment light-emitting diodes (LED), incandescent, fluorescent, gas discharge, or liquid crystal readouts either directly or indirectly.

Applications include instrument (e.g., counter, DVM, etc.) display driver, computer/calculator display driver, cockpit display driver, and various clock, watch, and timer uses.

- Low Logic Circuit Power Dissipation
- High-Current Sourcing Outputs (Up to 25 mA)
- · Latch Storage of Code
- Blanking Input
- · Lamp Test Provision
- · Readout Blanking on all Illegal Input Combinations
- Lamp Intensity Modulation Capability
- Time Share (Multiplexing) Facility
- Supply Voltage Range = 3.0 V to 18 V
- Capable of Driving Two Low-power TTL Loads, One Low-power Schottky TTL Load or Two HTL Loads Over the Rated Temperature Range
- Chip Complexity: 216 FETs or 54 Equivalent Gates
- Triple Diode Protection on all Inputs

MAXIMUM RATINGS* (Voltages Referenced to VSS)

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{DD}	- 0.5 to + 18	V
Input Voltage, All Inputs	V _{in}	-0.5 to V_{DD} +0.5	V
DC Current Drain per Input Pin	I	10	mA
Operating Temperature Range	T _A	- 55 to + 125	°C
Power Dissipation per Package†	PD	500	mW
Storage Temperature Range	T _{stg}	- 65 to + 150	°C
Maximum Output Drive Current (Source) per Output	lOHmax	25	mA
Maximum Continuous Output Power (Source) per Output ‡	POHmax	50	mW

POHmax = IOH (VDD - VOH)

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C Ceramic "L" Packages: - 12 mW/°C From 100°C To 125°C

MC14511B



I SUFFIX **CERAMIC** CASE 620



P SUFFIX PLASTIC CASE 648



D SUFFIX SOIC CASE 751B

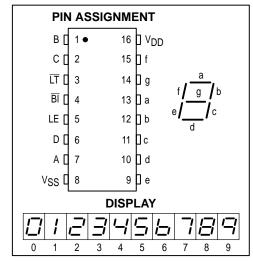


DW SUFFIX SOIC CASE 751G

ORDERING INFORMATION

MC14XXXBCP Plastic MC14XXXBCL Ceramic MC14XXXBDW SOIC SOIC MC14XXXBD

 $T_{\Delta} = -55^{\circ}$ to 125°C for all packages.



TRUTH TABLE

			Inpu	ıts						Out	puts			
LE	ВІ	LT	D	С	В	Α	а	b	С	d	е	f	g	Display
X	Х	0	Х	Х	Х	Х	1	1	1	1	1	1	1	8
X	0	1	Х	Х	Х	Х	0	0	0	0	0	0	0	Blank
0 0 0	1 1 1 1	1 1 1	0 0 0	0 0 0	0 0 1 1	0 1 1	1 0 1 1	1 1 1	1 1 1	1 0 1 1	1 0 0 0	1 0 0 0	0 0 1 1	0 1 2 3
0 0 0 0	1 1 1	1 1 1	0 0 0	1 1 1	0 0 1 1	0 1 0 1	0 1 0 1	1 0 0 1	1 1 1	0 1 1 0	0 0 1 0	1 1 1 0	1 1 1 0	4 5 6 7
0 0 0 0	1 1 1	1 1 1	1 1 1	0 0 0 0	0 0 1 1	0 1 0 1	1 1 0 0	1 1 0 0	1 1 0 0	1 0 0 0	1 0 0 0	1 1 0 0	1 1 0 0	8 9 Blank Blank
0 0 0	1 1 1	1 1 1	1 1 1	1 1 1	0 0 1 1	0 1 0 1	0 0 0	0 0 0	0 0 0	0 0 0	0 0 0	0 0 0 0	0 0 0	Blank Blank Blank Blank
1	1	1	Χ	Χ	Χ	Χ				*				*

^{*} Maximum Ratings are those values beyond which damage to the device may occur. †Temperature Derating:

X = Don't Care
* Depends upon the BCD code previously applied when LE = 0

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			V _{DD}	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Тур #	Max	Min	Max	Unit
Output Voltage "0 Vin = VDD or 0)" Level	VOL	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
V _{in} = 0 or V _{DD} "1	" Level	VOH	5.0 10 15	4.1 9.1 14.1		4.1 9.1 14.1	4.57 9.58 14.59	_ _ _	4.1 9.1 14.1	_ _ _	Vdc
Input Voltage # "0 (V _O = 3.8 or 0.5 Vdc) (V _O = 8.8 or 1.0 Vdc) (V _O = 13.8 or 1.5 Vdc))" Level	V _{IL}	5.0 10 15	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	Vdc
"1 (V _O = 0.5 or 3.8 Vdc) (V _O = 1.0 or 8.8 Vdc) (V _O = 1.5 or 13.8 Vdc)	" Level	VIH	5.0 10 15	3.5 7.0 11	111	3.5 7.0 11	2.75 5.50 8.25		3.5 7.0 11		Vdc
Output Drive Voltage (I _{OH} = 0 mA) (I _{OH} = 5.0 mA) (I _{OH} = 10 mA) (I _{OH} = 15 mA) (I _{OH} = 20 mA) (I _{OH} = 25 mA)	Source	VOH	5.0	4.1 — 3.9 — 3.4 —	11111	4.1 — 3.9 — 3.4 —	4.57 4.24 4.12 3.94 3.70 3.54	11111	4.1 — 3.5 — 3.0 —		Vdc
(I _{OH} = 0 mA) (I _{OH} = 5.0 mA) (I _{OH} = 10 mA) (I _{OH} = 15 mA) (I _{OH} = 20 mA) (I _{OH} = 25 mA)			10	9.1 — 9.0 — 8.6 —	1 1 1 1 1	9.1 — 9.0 — 8.6 —	9.58 9.26 9.17 9.04 8.90 8.70	 - - - -	9.1 — 8.6 — 8.2 —	_ _ _ _ _	Vdc
(I _{OH} = 0 mA) (I _{OH} = 5.0 mA) (I _{OH} = 10 mA) (I _{OH} = 15 mA) (I _{OH} = 20 mA) (I _{OH} = 25 mA)			15	14.1 — 14 — 13.6 —		14.1 — 14 — 13.6 —	14.59 14.27 14.18 14.07 13.95 13.70	 - - - -	14.1 — 13.6 — 13.2 —	_ _ _ _ _	Vdc
Output Drive Current (V _{OL} = 0.4 V) (V _{OL} = 0.5 V) (V _{OL} = 1.5 V)	Sink	lol	5.0 10 15	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.25 8.8		0.36 0.9 2.4		mAdc
Input Current		l _{in}	15	_	± 0.1	_	±0.00001	± 0.1	_	± 1.0	μAdc
Input Capacitance Quiescent Current (Per Package) V _{in} = 0 or I _{out} = 0 μA	V _{DD} ,	C _{in}	5.0 10 15		5.0 10 20		5.0 0.005 0.010 0.015	7.5 5.0 10 20		150 300 600	pF μAdc
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs buffers switching)		lΤ	5.0 10 15			$I_T = (3$	I .9 μA/kHz) f 3.8 μA/kHz) f 5.7 μA/kHz) f	+ I _{DD}			μAdc

#Noise immunity specified for worst–case input combination.

Noise Margin for both "1" and "0" level =

1.0 Vdc min @ V_{DD} = 5.0 Vdc 2.0 Vdc min @ V_{DD} = 10 Vdc 2.5 Vdc min @ V_{DD} = 15 Vdc

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + 3.5 \times 10^{-3} (C_L - 50) \text{ V}_{DD}f$$

where: IT is in μA (per package), C_L in pF, V_{DD} in Vdc, and f in kHz is input frequency.

^{**}The formulas given are for the typical characteristics only at 25 $^{\circ}\text{C}.$

SWITCHING CHARACTERISTICS* ($C_L = 50 \text{ pF}, T_A = 25^{\circ}C$)

Characteristic	Symbol	V _{DD} Vdc	Min	Тур	Max	Unit
Output Rise Time $t_{TLH} = (0.40 \text{ ns/pF}) \text{ C}_L + 20 \text{ ns}$ $t_{TLH} = (0.25 \text{ ns/pF}) \text{ C}_L + 17.5 \text{ ns}$ $t_{TLH} = (0.20 \text{ ns/pF}) \text{ C}_L + 15 \text{ ns}$	tтLH	5.0 10 15	_ _ _	40 30 25	80 60 50	ns
Output Fall Time $t_{THL} = (1.5 \text{ ns/pF}) \text{ C}_{L} + 50 \text{ ns}$ $t_{THL} = (0.75 \text{ ns/pF}) \text{ C}_{L} + 37.5 \text{ ns}$ $t_{THL} = (0.55 \text{ ns/pF}) \text{ C}_{L} + 37.5 \text{ ns}$	t⊤HL	5.0 10 15	_ _ _	125 75 65	250 150 130	ns
Data Propagation Delay Time $tp_{LH} = (0.40 \text{ ns/pF}) \text{ C}_L + 620 \text{ ns}$ $tp_{LH} = (0.25 \text{ ns/pF}) \text{ C}_L + 237.5 \text{ ns}$ $tp_{LH} = (0.20 \text{ ns/pF}) \text{ C}_L + 165 \text{ ns}$	[†] PLH	5.0 10 15	_ _ _	640 250 175	1280 500 350	ns
$t_{PHL} = (1.3 \text{ ns/pF}) C_L + 655 \text{ ns}$ $t_{PHL} = (0.60 \text{ ns/pF}) C_L + 260 \text{ ns}$ $t_{PHL} = (0.35 \text{ ns/pF}) C_L + 182.5 \text{ ns}$	^t PHL	5.0 10 15		720 290 200	1440 580 400	
Blank Propagation Delay Time tpLH = (0.30 ns/pF) C _L + 585 ns tpLH = (0.25 ns/pF) C _L + 187.5 ns tpLH = (0.15 ns/pF) C _L + 142.5 ns	^t PLH	5.0 I0 15	_ _ _	600 200 150	750 300 220	ns
$t_{PHL} = (0.85 \text{ ns/pF}) C_L + 442.5 \text{ ns}$ $t_{PHL} = (0.45 \text{ ns/pF}) C_L + 177.5 \text{ ns}$ $t_{PHL} = (0.35 \text{ ns/pF}) C_L + 142.5 \text{ ns}$	^t PHL	5.0 10 15	_ _ _	485 200 160	970 400 320	
Tamp Test Propagation Delay Time tpLH = (0.45 ns/pF) C _L + 290.5 ns tpLH = (0.25 ns/pF) C _L + 112.5 ns tpLH = (0.20 ns/pF) C _L + 80 ns	[†] PLH	5.0 10 15	_ _ _	313 125 90	625 250 180	ns
$t_{PHL} = (1.3 \text{ ns/pF}) C_L + 248 \text{ ns}$ $t_{PHL} = (0.45 \text{ ns/pF}) C_L + 102.5 \text{ ns}$ $t_{PHL} = (0.35 \text{ ns/pF}) C_L + 72.5 \text{ ns}$	^t PHL	5.0 10 15	_ _ _	313 125 90	625 250 180	
Setup Time	t _{su}	5.0 10 15	100 40 30	_ _ _	_ _ _	ns
Hold Time	th	5.0 10 15	60 40 30	_ _ _	_ _ _	ns
Latch Enable Pulse Width	tWL	5.0 10 15	520 220 130	260 110 65	_ _ _	ns

^{*} The formulas given are for the typical characteristics only.

This device contains protection circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high-impedance circuit. A destructive high current mode may occur if V_{in} and V_{out} are not constrained to the range $V_{SS} \le (V_{in})$ or $V_{out} \le V_{DD}$.

Due to the sourcing capability of this circuit, damage can occur to the device if V_{DD} is applied, and the outputs are shorted to V_{SS} and are at a logical 1 (See Maximum Ratings).

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either VSS or VDD).

Input LE low, and Inputs D, \overline{BI} and \overline{LT} high. f in respect to a system clock.

All outputs connected to respective C_L loads.

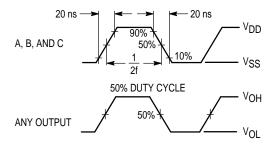
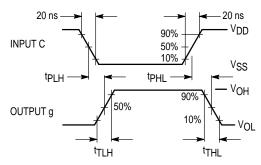
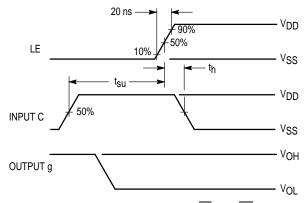


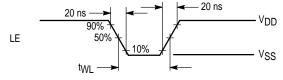
Figure 1. Dynamic Power Dissipation Signal Waveforms



(a) Inputs D and LE low, and Inputs A, B, \overline{BI} and \overline{LT} high.



(b) Input D low, Inputs A, B, \overline{BI} and \overline{LT} high.

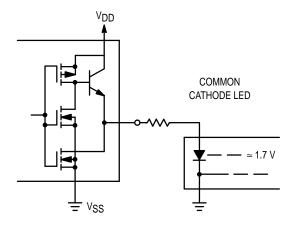


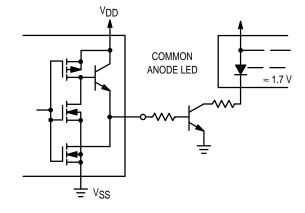
(c) Data DCBA strobed into latches.

Figure 2. Dynamic Signal Waveforms

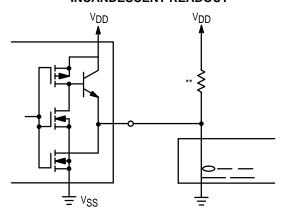
CONNECTIONS TO VARIOUS DISPLAY READOUTS

LIGHT EMITTING DIODE (LED) READOUT

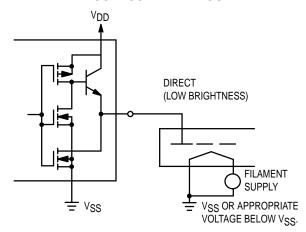




INCANDESCENT READOUT

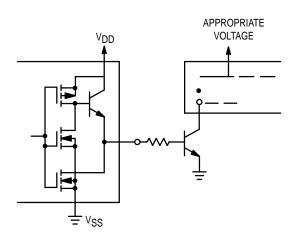


FLUORESCENT READOUT



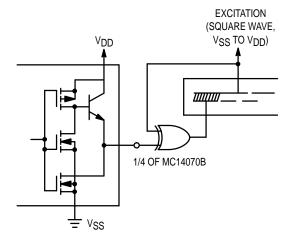
(CAUTION: Maximum working voltage = 18.0 V)

GAS DISCHARGE READOUT



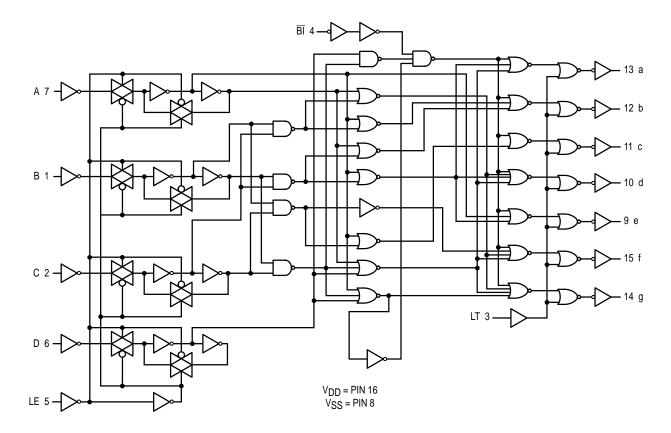
^{**} A filament pre—warm resistor is recommended to reduce filament thermal shock and increase the effective cold resistance of the filament.

LIQUID CRYSTAL (LCD) READOUT



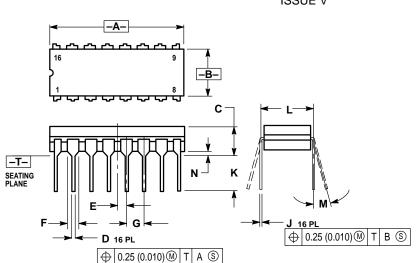
Direct dc drive of LCD's not recommended for life of LCD readouts.

LOGIC DIAGRAM



OUTLINE DIMENSIONS

L SUFFIX CERAMIC DIP PACKAGE CASE 620-10 ISSUE V



NOTES:

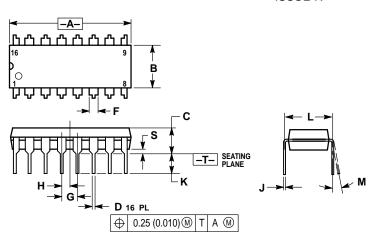
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN
 FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030)
 WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	BSC	7.62 BSC		
М	0°	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	

P SUFFIX

PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

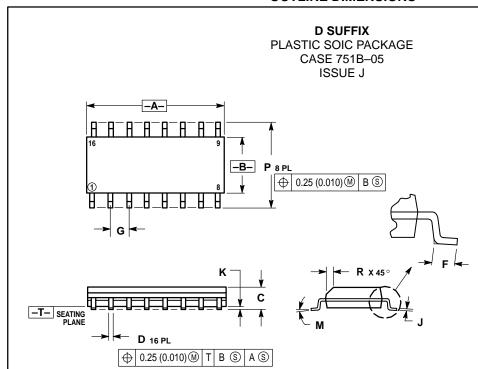
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

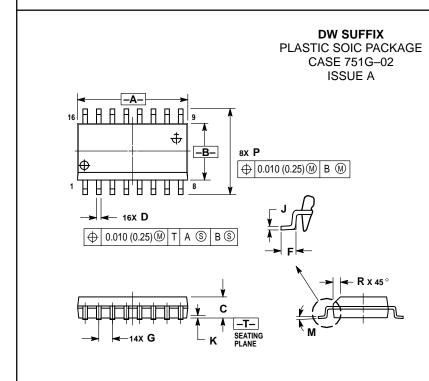
OUTLINE DIMENSIONS



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR
- PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
U	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
7	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	10.15	10.45	0.400	0.411		
В	7.40	7.60	0.292	0.299		
С	2.35	2.65	0.093	0.104		
D	0.35	0.49	0.014	0.019		
F	0.50	0.90	0.020	0.035		
G	1.27	BSC	0.050 BSC			
J	0.25	0.32	0.010	0.012		
K	0.10	0.25	0.004	0.009		
M	0°	7°	0 °	7°		
Р	10.05	10.55	0.395	0.415		
R	0.25	0.75	0.010	0.029		

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